# intersil

#### Data Sheet

#### July 25, 2011

#### FN6378.4

### 34μΑ Micro-power Single and Dual Rail-to-Rail Input-Output (RRIO) Low Input Bias Current Op Amps

The ISL28168 and ISL28268 are micro-power operational amplifiers optimized for single supply operation over a power supply range of 2.4VDC to 5.5VDC. These devices draw minimal supply current and operate rail-to-rail at the input and output, while providing excellent DC-accuracy, noise and output drive specifications. Competing devices seriously degrade these parameters to achieve micro-power supply current.

The parts feature an Input Range Enhancement Circuit (IREC), which enables them to maintain CMRR performance for input voltages greater than the positive supply. The input signal is capable of swinging 0.25V above the positive supply and to 100mV below the negative supply with only a slight degradation of the CMRR performance. The output operation is rail-to-rail.

The 1/f corner of the voltage noise spectrum is at 100Hz. This results in low frequency noise performance, which can only be found on devices with an order of magnitude higher supply current.

ISL28168 and ISL28268 can be operated from one lithium cell or two Ni-Cd batteries. The ISL28168 contains an enable pin feature that allows the device to be shutdown when not in use.

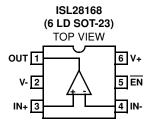
#### Features

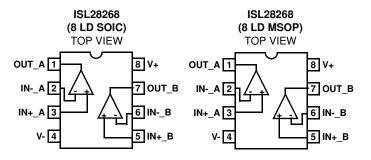
- 34µA typical supply current
- 10pA typical input bias current
- 200kHz gain bandwidth product
- 2.4V to 5.5V single supply voltage range
- · Rail-to-rail input and output
- Enable pin (ISL28168 only)
- Pb-free (RoHS compliant)

#### Applications

- Battery- or solar-powered systems
- 4mA to 20mA current loops
- Handheld consumer products
- Medical devices
- · Sensor amplifiers
- ADC buffers
- · DAC output amplifiers

#### Pinouts





## Pin Descriptions

ISL28168 (6 Ld SOT-23)	ISL28268 (8 Ld SOIC) (8 Ld MSOP)	PIN NAME	FUNCTION	EQUIVALENT CIRCUIT
4	2 (A) 6 (B)	IN- INA INB	Inverting input	
3	3 (A) 5 (B)	IN+ IN+_A IN+_B	Non-inverting input	See Circuit 1
2	4	V-	Negative supply	V+ CAPACITIVELY COUPLED ESD CLAMP V- CIRCUIT 2
1	1 (A) 7 (B)	OUT OUT_A OUT_B	Output	····
6	8	V+	Positive supply	See Circuit 2
5		ĒN	Chip enable	LOGIC PIN CIRCUIT 3

### **Ordering Information**

PART NUMBER (Notes 3, 4)	PART MARKING	PACKAGE (Pb-free)	PKG. DWG. #
ISL28168FHZ-T7 (Note 1)	GACA (Note 5)	6 Ld SOT-23	P6.064A
ISL28168FHZ-T7A (Note 1)	GACA (Note 5)	6 Ld SOT-23	P6.064A
ISL28268FBZ (Note 2)	28268 FBZ	8 Ld SOIC	M8.15E
ISL28268FUZ (Note 2)	8268Z	8 Ld MSOP	M8.118A
ISL28168EVAL1Z	Evaluation Board - 6 Ld SOT-23		I
ISL28268SOICEVAL1Z	Evaluation Board - 8 Ld SOIC		
SL28268MSOPEVAL1Z	Evaluation Board - 8 Ld MSOP		

1. Please refer to TB347 for details on reel specifications.

2. Add "-T\*" suffix for tape and reel. Please refer to TB347 for details on reel specifications

3. These Intersil Pb-free plastic packaged products employ special Pb-free material sets, molding compounds/die attach materials, and 100% matte tin plate plus anneal (e3 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations). Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.

4. For Moisture Sensitivity Level (MSL), please see device information page for <u>ISL28168</u>. ISL28268. For more information on MSL please see techbrief <u>TB363</u>.

5. The part marking is located on the bottom of the part.

#### Absolute Maximum Ratings (T<sub>A</sub> = +25°C)

Supply Voltage         5.75V           Supply Turn-on Voltage Slew Rate         1V/µs           Differential Input Current         5mA           Differential Input Voltage         0.5V           Input Voltage         V- 0.5V to V+ + 0.5V
ESD Rating Human Body Model

#### **Thermal Information**

Thermal Resistance (Note 6)	$\theta_{JA} (^{\circ}C/W)$
6 Ld SOT-23 Package	230
8 Ld SOIC Package	120
8 Ld MSOP Package	160
Output Short-Circuit Duration	
Ambient Operating Temperature Range40°	C to +125°C
Storage Temperature Range65°	C to +150°C
Operating Junction Temperature	+125°C
Pb-Free Reflow Profilesee link below	
http://www.intersil.com/pbfree/Pb-FreeReflow.asp	

CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.

NOTE:

6. θ<sub>JA</sub> is measured with the component mounted on a high effective thermal conductivity test board in free air. See Tech Brief <u>TB379</u> for details.

IMPORTANT NOTE: All parameters having Min/Max specifications are guaranteed. Typical values are for information purposes only. Unless otherwise noted, all tests are at the specified temperature and are pulsed tests, therefore:  $T_J = T_C = T_A$ 

**Electrical Specifications**  $V_{+} = 5V$ ,  $V_{-} = 0V$ ,  $V_{CM} = 2.5V$ ,  $R_{L} = Open$ ,  $T_{A} = +25^{\circ}C$  unless otherwise specified. Boldface limits apply over the operating temperature range, -40°C to +125°C. Temperature data established by characterization.

PARAMETER	DESCRIPTION	CONDITIONS	MIN (Note 7)	ТҮР	MAX (Note 7)	UNIT
DC SPECIFICA	TIONS		1		1	
V <sub>OS</sub>	Input Offset Voltage	ISL28168	-1.6 <b>-1.8</b>	±0.09	1.6 <b>1.8</b>	mV
		ISL28268	-2.4 <b>-2.6</b>	±0.09	2.4 <b>2.6</b>	mV
$\frac{\Delta V_{OS}}{\Delta T}$	Input Offset Voltage vs Temperature			0.3		µV/°C
I <sub>OS</sub>	Input Offset Current	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	-35 <b>-80</b>	±5	35 <b>80</b>	pА
IB	Input Bias Current	$T_A = -40^{\circ}C$ to $+85^{\circ}C$	-30 <b>-80</b>	±10	30 <b>80</b>	pА
CMIR	Common-Mode Voltage Range	Guaranteed by CMRR	0		5	V
CMRR	Common-Mode Rejection Ratio	V <sub>CM</sub> = 0V to 5V	75 <b>70</b>	98		dB
PSRR	Power Supply Rejection Ratio	V <sub>+</sub> = 2.4V to 5.5V	80 <b>75</b>	98		dB
A <sub>VOL</sub>	Large Signal Voltage Gain	$V_{O}$ = 0.5V to 4.5V, $R_{L}$ = 100k $\Omega$ to $V_{CM}$	100 <b>75</b>	220		V/mV
		$V_O$ = 0.5V to 4.5V, $R_L$ = 1k\Omega to $V_{CM}$		45	1.8 2.4 2.6 35 80 30 80	V/mV
V <sub>OUT</sub>	Maximum Output Voltage Swing	Output low, $R_L = 100 k\Omega$ to $V_{CM}$		5.5	-	mV
		Output low, $R_L = 1k\Omega$ to $V_{CM}$		135		mV
		Output high, $R_L = 100 k\Omega$ to $V_{CM}$	4.992 <b>4.990</b>	4.995		V
		Output high, $R_L = 1k\Omega$ to $V_{CM}$	4.84 <b>4.77</b>	4.874		V
I <sub>S,ON</sub>	Quiescent Supply Current, Enabled	Per Amp		34	-	μA

#### **Electrical Specifications**

 $V_+ = 5V$ ,  $V_- = 0V$ ,  $V_{CM} = 2.5V$ ,  $R_L = Open$ ,  $T_A = +25^{\circ}C$  unless otherwise specified. Boldface limits apply over the operating temperature range, -40°C to +125°C. Temperature data established by characterization. (Continued)

PARAMETER	DESCRIPTION	CONDITIONS	MIN (Note 7)	ТҮР	MAX (Note 7)	UNIT
I <sub>S,OFF</sub>	Quiescent Supply Current, Disabled (ISL28168)			10	14 <b>19</b>	μA
I <sub>O</sub> +	Short-Circuit Output Source Current	$R_L = 10\Omega$ to $V_{CM}$	27 <b>15</b>	30		mA
I <sub>O</sub> -	Short-Circuit Output Sink Current	$R_L = 10\Omega$ to $V_{CM}$		-25	-22 <b>-15</b>	mA
V <sub>SUPPLY</sub>	Supply Operating Range	V <sub>+</sub> to V <sub>-</sub>	2.4		5.5	V
V <sub>INH</sub>	EN Pin High Level (ISL28168)		2			V
V <sub>INL</sub>	EN Pin Low Level (ISL28168)				0.8	V
IENH	EN Pin Input High Current (ISL28168)	$V_{\overline{EN}} = V_+$		1	1.5 <b>1.6</b>	μA
I <sub>ENL</sub>	EN Pin Input Low Current (ISL28168)	$V_{\overline{EN}} = V_{-}$		12	25 <b>30</b>	nA
AC SPECIFICAT	TIONS	l				
GBW	Gain Bandwidth Product			200		kHz
Unity Gain Bandwidth	-3dB Bandwidth	$A_V = 1, R_F = 0\Omega, V_{OUT} = 10mV_{P-P}, R_L = 10k\Omega$ to $V_{CM}$		420		kHz
e <sub>N</sub>	Input Noise Voltage Peak-to-Peak	f = 0.1Hz to 10Hz		1.4		$\mu V_{P-P}$
	Input Noise Voltage Density	f <sub>O</sub> = 1kHz		64		nV/√Hz
i <sub>N</sub>	Input Noise Current Density	f <sub>O</sub> = 10kHz		0.19		pA/√Hz
CMRR @ 60Hz	Input Common Mode Rejection Ratio	$V_{CM} = 1V_{P-P}$ , $R_L = 10k\Omega$ to $V_{CM}$		-70		dB
PSRR+ @ 120Hz	Power Supply Rejection Ratio - +V	$V_+, V = \pm 1.2V$ and $\pm 2.5V$ , V <sub>SOURCE</sub> = $1V_{P-P}$ , $R_L = 10k\Omega$ to $V_{CM}$		-64		dB
PSRR- @ 120Hz	Power Supply Rejection RatioV	$V_+, V = \pm 1.2V$ and $\pm 2.5V$ $V_{SOURCE} = 1V_{P-P}$ , $R_L = 10k\Omega$ to $V_{CM}$		-85		dB
TRANSIENT RE	SPONSE					
SR	Slew Rate			0.1		V/µs
t <sub>r</sub> , t <sub>f</sub> , Large Signal	Rise Time, 10% to 90%, V <sub>OUT</sub>	$\begin{array}{l} A_V = +2, \ V_{OUT} = 1 V_{P-P}, \ R_g = R_f = 10 k \Omega \\ R_L = 10 k \Omega \ to \ V_{CM} \end{array}$		10		μs
	Fall Time, 90% to 10%, V <sub>OUT</sub>	$\begin{array}{l} A_V = +2, \ V_{OUT} = 1 V_{P-P}, \ R_g = R_f = 10 k \Omega \\ R_L = 10 k \Omega \ to \ V_{CM} \end{array}$		9		μs
t <sub>r</sub> , t <sub>f</sub> , Small Signal	Rise Time, 10% to 90%, V <sub>OUT</sub>	$\begin{array}{l} A_V = +2, \ V_{OUT} = 10mV_{P-P}, \\ R_g = R_f = R_L = 10k\Omega \ to \ V_{CM} \end{array}$		650		ns
	Fall Time, 90% to 10%, V <sub>OUT</sub>	$\begin{array}{l} A_V = +2, \ V_{OUT} = 10mV_{P-P}, \\ R_g = R_f = R_L = 10k\Omega \ to \ V_{CM} \end{array}$		640		ns
t <del>EN</del>	Enable to Output Turn-on Delay Time, 10% EN to 10% V <sub>OUT</sub> , (ISL28168)			15		μs
	Enable to Output Turn-off Delay Time, 10% EN to 10% V <sub>OUT</sub> , (ISL28168)	$V_{\overline{EN}} = 0V$ to 5V, $A_V = +2$ , $R_g = R_f = R_L = 1k$ to $V_{CM}$		0.5		μs

NOTE:

7. Compliance to datasheet limits is assured by one or more methods: production test, characterization and/or design.

### **Typical Performance Curves** $V_{+} = 5V$ , $V_{-} = 0V$ , $V_{CM} = 2.5V$ , $R_{L} = Open$

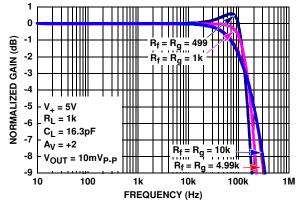


FIGURE 1. GAIN vs FREQUENCY vs FEEDBACK RESISTOR VALUES  ${\rm R_f/R_d}$ 

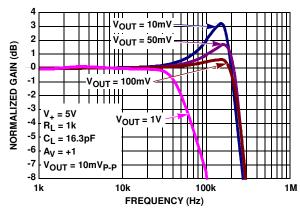


FIGURE 2. GAIN vs FREQUENCY vs V<sub>OUT</sub>, R<sub>L</sub> = 1k

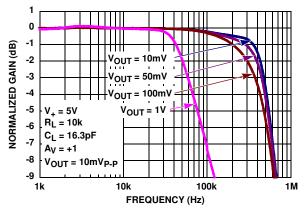


FIGURE 3. GAIN vs FREQUENCY vs V<sub>OUT</sub>, R<sub>L</sub> = 10k

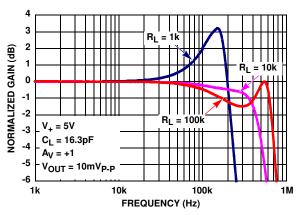


FIGURE 5. GAIN vs FREQUENCY vs RL

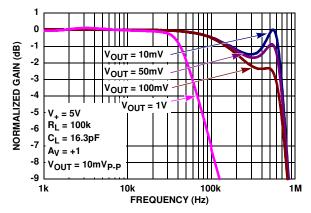


FIGURE 4. GAIN vs FREQUENCY vs  $V_{OUT}$ ,  $R_L = 100k$ 

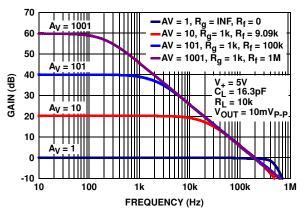


FIGURE 6. FREQUENCY RESPONSE vs CLOSED LOOP GAIN

Typical Performance Curves V<sub>+</sub> = 5V, V<sub>-</sub> = 0V, V<sub>CM</sub> = 2.5V, R<sub>L</sub> = Open (Continued)

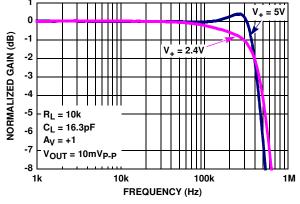


FIGURE 7. GAIN vs FREQUENCY vs SUPPLY VOLTAGE

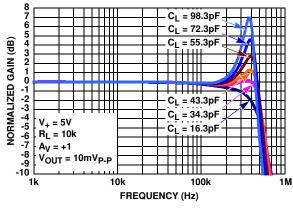


FIGURE 8. GAIN vs FREQUENCY vs CL

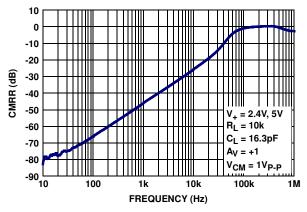


FIGURE 9. CMRR vs FREQUENCY, V<sub>+</sub> = 2.4V AND 5V

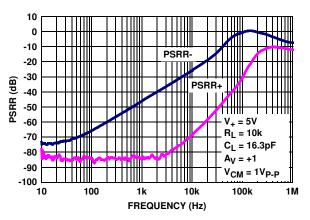


FIGURE 11. PSRR vs FREQUENCY, V<sub>+</sub>, V<sub>-</sub> = ±1.2V

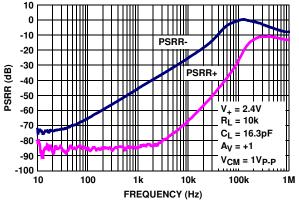


FIGURE 10. PSRR vs FREQUENCY, V<sub>+</sub>, V<sub>-</sub> = ±1.2V

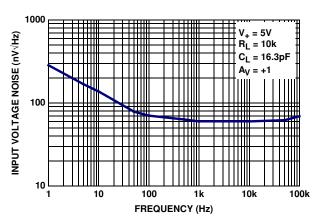


FIGURE 12. INPUT VOLTAGE NOISE DENSITY vs FREQUENCY

Typical Performance Curves  $V_{+} = 5V$ ,  $V_{-} = 0V$ ,  $V_{CM} = 2.5V$ ,  $R_{L} = Open$  (Continued)

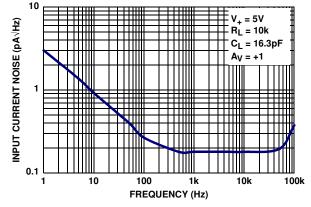


FIGURE 13. INPUT CURRENT NOISE DENSITY vs FREQUENCY

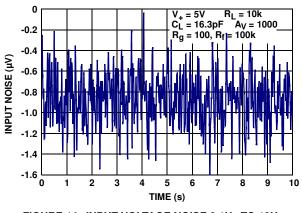
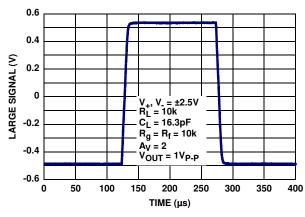
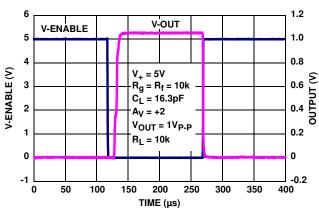


FIGURE 14. INPUT VOLTAGE NOISE 0.1Hz TO 10Hz









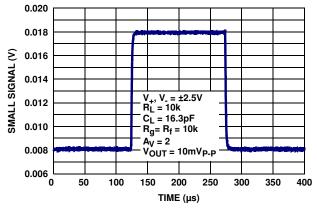
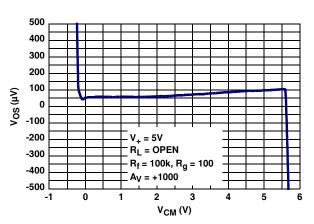


FIGURE 16. SMALL SIGNAL STEP RESPONSE





Typical Performance Curves  $V_{+} = 5V$ ,  $V_{-} = 0V$ ,  $V_{CM} = 2.5V$ ,  $R_{L} = Open$  (Continued)

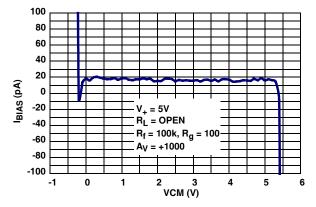
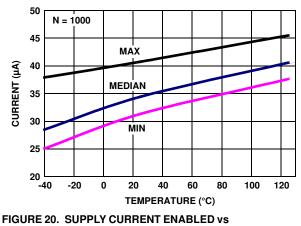


FIGURE 19. INPUT BIAS CURRENT vs COMMON MODE INPUT VOLTAGE



TEMPERATURE,  $V_+$ ,  $V_- = \pm 2.5V$ 

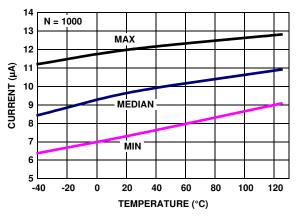


FIGURE 21. SUPPLY CURRENT DISABLED vs TEMPERATURE, V<sub>+</sub>, V<sub>-</sub> =  $\pm 2.5V$ 

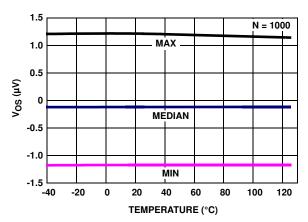


FIGURE 23. V<sub>OS</sub> (SOT PKG) vs TEMPERATURE, V<sub>IN</sub> = 0V, V<sub>+</sub>, V<sub>-</sub> = ±2.5V

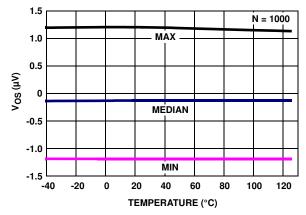
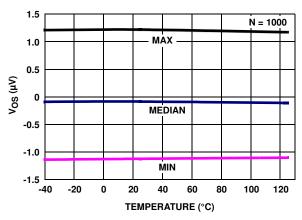
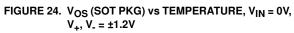
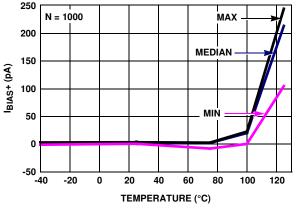


FIGURE 22. V<sub>OS</sub> (SOT PKG) vs TEMPERATURE, V<sub>IN</sub> = 0V, V<sub>+</sub>, V<sub>-</sub> =  $\pm 2.75$ V





Typical Performance Curves  $V_{+} = 5V$ ,  $V_{-} = 0V$ ,  $V_{CM} = 2.5V$ ,  $R_{L} = Open$  (Continued)





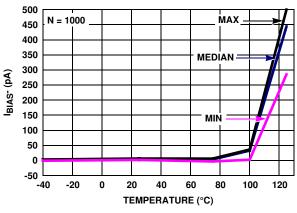


FIGURE 26. IBIAS- vs TEMPERATURE, V+, V\_ = ±2.5V

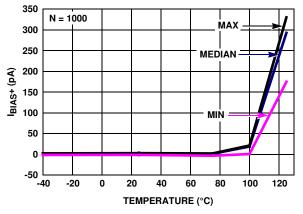


FIGURE 27. IBIAS+ vs TEMPERATURE, V+, V- = ±1.2V

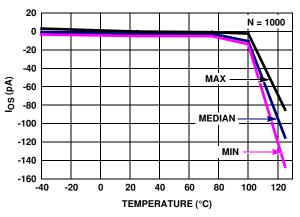


FIGURE 29. I<sub>OS</sub> vs TEMPERATURE, V<sub>+</sub>, V<sub>-</sub> = ±2.5

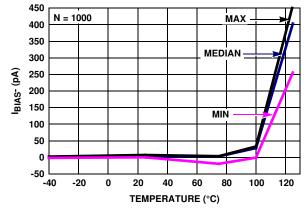


FIGURE 28. I<sub>BIAS</sub>- vs TEMPERATURE, V<sub>+</sub>, V<sub>-</sub> = ±1.2V

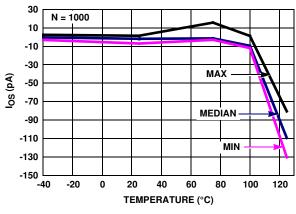
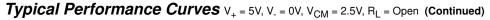
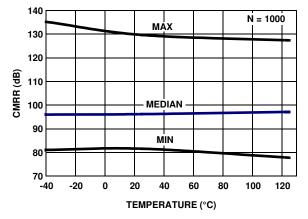


FIGURE 30. I<sub>OS</sub> vs TEMPERATURE, V<sub>+</sub>, V<sub>-</sub> = ±1.2V







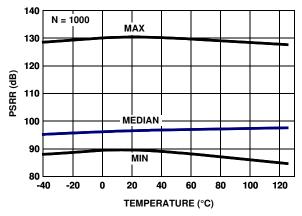


FIGURE 32. PSRR vs TEMPERATURE, V<sub>+</sub>, V<sub>-</sub> = ±1.2V TO ±2.75V

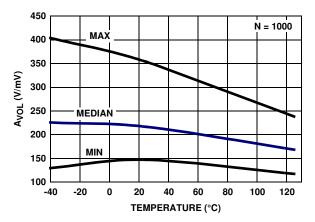


FIGURE 33. A<sub>VOL</sub> vs TEMPERATURE, V<sub>+</sub>, V<sub>-</sub> = ±2.5V, V<sub>O</sub> = -2V TO +2V, R<sub>L</sub> = 100k

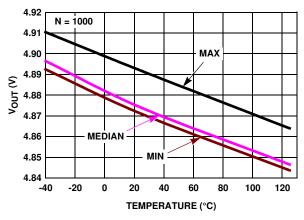


FIGURE 35. V<sub>OUT</sub> HIGH vs TEMPERATURE, V<sub>+</sub>, V<sub>-</sub> = ±2.5V,  $R_L$  = 1k

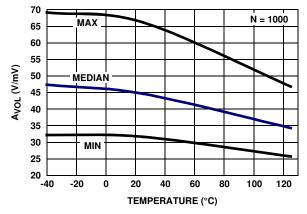
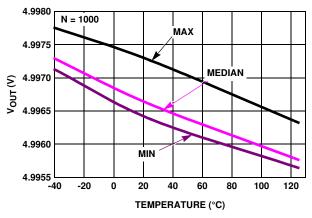
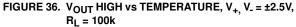
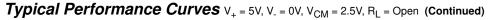


FIGURE 34. A<sub>VOL</sub> vs TEMPERATURE, V<sub>+</sub>, V<sub>-</sub> = ±2.5V, V<sub>O</sub> = -2V TO +2V, R<sub>L</sub> = 1k







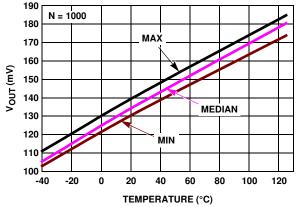


FIGURE 37. V<sub>OUT</sub> LOW vs TEMPERATURE, V<sub>+</sub>, V<sub>-</sub> = ±2.5V,  $R_L$  = 1k

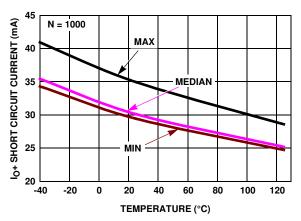


FIGURE 39. I<sub>O</sub>+ SHORT CIRCUIT OUTPUT CURRENT vs TEMPERATURE, V<sub>IN</sub> = -2.55V, R<sub>L</sub> = 10k, V<sub>+</sub>, V<sub>-</sub> =  $\pm$ 2.5V

### Applications Information

#### Introduction

The ISL28168 is a single CMOS rail-to-rail input, output (RRIO) operational amplifier with an enable feature. The ISL28268 is a dual version without the enable feature. Both devices are designed to operate from single supply (2.4V to 5.5V) or dual supplies (±1.2V to ±2.75V).

#### Rail-to-Rail Input/Output

Many rail-to-rail input stages use two differential input pairs, a long-tail PNP (or PFET) and an NPN (or NFET). Severe penalties have to be paid for this circuit topology. As the input signal moves from one supply rail to another, the operational amplifier switches from one input pair to the other causing drastic changes in input offset voltage and an undesired change in magnitude and polarity of input offset current.

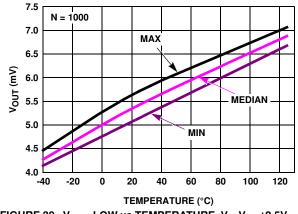


FIGURE 38. V<sub>OUT</sub> LOW vs TEMPERATURE, V<sub>+</sub>, V<sub>-</sub> =  $\pm$ 2.5V, R<sub>L</sub> = 100k

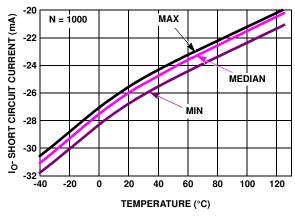


FIGURE 40. I<sub>O</sub>- SHORT CIRCUIT OUTPUT CURRENT vs TEMPERATURE, V<sub>IN</sub> = +2.55V, R<sub>L</sub> = 10k, V<sub>+</sub>, V<sub>-</sub> =  $\pm 2.5V$ 

The ISL28168 and ISL28268 achieve input rail-to-rail operation without sacrificing important precision specifications and degrading distortion performance. The devices' input offset voltage exhibits a smooth behavior throughout the entire common-mode input range. The input bias current versus the common-mode voltage range gives us an undistorted behavior from typically 100mV below the negative rail, and 0.25V higher than the V+ rail. The CMOS output stage features excellent drive capability, typically swinging to within 6mV of either rail with a 100k $\Omega$  load.

#### Results of Over-Driving the Output

Caution should be used when over-driving the output for long periods of time. Over-driving the output can occur in two ways.

1. The input voltage times the gain of the amplifier exceeds the supply voltage by a large value

2. The output current required is higher than the output stage can deliver. These conditions can result in a shift in the Input Offset Voltage ( $V_{OS}$ ) as much as 1 $\mu$ V/hr. of exposure under these conditions.

#### IN+ and IN- Input Protection

All input terminals have internal ESD protection diodes to both positive and negative supply rails, limiting the input voltage to within one diode beyond the supply rails. They also contain back-to-back diodes across the input terminals (see "Pin Descriptions" on page 2 - Circuit 1). For applications where the input differential voltage is expected to exceed 0.5V, an external series resistor must be used to ensure the input currents never exceed 5mA (see Figure 41).

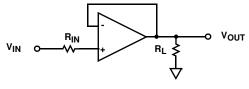


FIGURE 41. INPUT CURRENT LIMITING

#### Enable/Disable Feature

The ISL28168 offers an EN pin that disables the device when pulled up to at least 2.0V. In the disabled state (output in a high impedance state), the part consumes typically 10µA at room temperature. By disabling the part, multiple ISL28168 parts can be connected together as a MUX. In this configuration, the outputs are tied together in parallel and a channel can be selected by the EN pin. The loading effects of the feedback resistors of the disabled amplifier must be considered when multiple amplifier outputs are connected together. Note that feed through from the IN+ to IN- pins occurs on any Mux Amp disabled channel where the input differential voltage exceeds 0.5V (e.g., active channel  $V_{OUT} = 1V$ , while disabled channel  $V_{IN} = GND$ ), so the Mux implementation is best suited for small signal applications. If large signals are required, use series IN+ resistors, or large value R<sub>F</sub>, to keep the feed-through current low enough to minimize the impact on the active channel. See "Limitations of the Differential Input Protection" on page 13 for more details.

To disable the part, the user needs to supply the  $1.5\mu$ A required to pull the  $\overline{EN}$  pin to the V<sub>+</sub> rail. If left open, the  $\overline{EN}$  pin will pull to the negative rail and the device will be enabled by default. If the  $\overline{EN}$  function is not required (no need to turn the part off), as a precaution, it is recommended that the user tie the  $\overline{EN}$  pin to the V<sub>-</sub> pin.

#### Limitations of the Differential Input Protection

If the input differential voltage is expected to exceed 0.5V, an external current limiting resistor must be used to ensure the input current never exceeds 5mA. For non inverting unity gain applications, the current limiting can be via a series IN+ resistor, or via a feedback resistor of appropriate value. For other gain configurations, the series IN+ resistor is the best

choice, unless the feedback  $({\rm R}_F)$  and gain setting  $({\rm R}_G)$  resistors are both sufficiently large to limit the input current to 5mA.

Large differential input voltages can arise from several sources:

- 1. During open loop (comparator) operation. Used this way, the IN+ and IN- voltages don't track, so differentials arise.
- 2. When the amplifier is disabled but an input signal is still present. An R<sub>L</sub> or R<sub>G</sub> to GND keeps the IN- at GND, while the varying IN+ signal creates a differential voltage. Mux Amp applications are similar, except that the active channel V<sub>OUT</sub> determines the voltage on the IN- terminal.
- When the slew rate of the input pulse is considerably faster than the op amp's slew rate. If the V<sub>OUT</sub> can't keep up with the IN+ signal, a differential voltage results, and visible distortion occurs on the input and output signals. To avoid this issue, keep the input slew rate below 0.1V/μs, or use appropriate current limiting resistors.

Large (>2V) differential input voltages can also cause an increase in disabled  $I_{CC}. \label{eq:large}$ 

#### Using Only One Channel

The ISL28268 is a dual op amp. If the application only requires one channel, the user must configure the unused channel to prevent it from oscillating. The unused channel will oscillate if the input and output pins are floating. This will result in higher than expected supply currents and possible noise injection into the channel being used. The proper way to prevent this oscillation is to short the output to the negative input and ground the positive input (as shown in Figure 42).



#### FIGURE 42. PREVENTING OSCILLATIONS IN UNUSED CHANNELS

#### Proper Layout Maximizes Performance

To achieve the maximum performance of the high input impedance and low offset voltage, care should be taken in the circuit board layout. The PC board surface must remain clean and free of moisture to avoid leakage currents between adjacent traces. Surface coating of the circuit board will reduce surface moisture and provide a humidity barrier, reducing parasitic resistance on the board. When input leakage current is a concern, the use of guard rings around the amplifier inputs will further reduce leakage currents. Figure 43 shows a guard ring example for a unity gain amplifier that uses the low impedance amplifier output at the same voltage as the high impedance input to eliminate surface leakage. The guard ring does not need to be a specific width, but it should form a continuous loop around both inputs. For further reduction of leakage currents, components can be mounted to the PC board using Teflon standoff insulators.

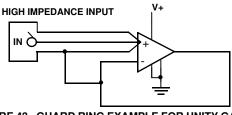


FIGURE 43. GUARD RING EXAMPLE FOR UNITY GAIN AMPLIFIER

#### **Current Limiting**

These devices have no internal current-limiting circuitry. If the output is shorted, it is possible to exceed the Absolute Maximum Rating for output current or power dissipation, potentially resulting in the destruction of the device.

#### **Power Dissipation**

It is possible to exceed the +125°C maximum junction temperatures under certain load and power-supply conditions. It is therefore important to calculate the maximum junction temperature ( $T_{JMAX}$ ) for all applications to determine if power supply voltages, load conditions, or package type need to be modified to remain in the safe operating area. These parameters are related in Equation 1:

$$T_{JMAX} = T_{MAX} + (\theta_{JA} x PD_{MAXTOTAL})$$
(EQ. 1)

where:

- P<sub>DMAXTOTAL</sub> is the sum of the maximum power dissipation of each amplifier in the package (PD<sub>MAX</sub>)
- PD<sub>MAX</sub> for each amplifier can be calculated using Equation 2:

$$PD_{MAX} = 2^{*}V_{S} \times I_{SMAX} + (V_{S} - V_{OUTMAX}) \times \frac{V_{OUTMAX}}{R_{L}}$$
(EQ. 2)

where:

- T<sub>MAX</sub> = Maximum ambient temperature
- $\theta_{JA}$  = Thermal resistance of the package
- PD<sub>MAX</sub> = Maximum power dissipation of 1 amplifier
- V<sub>S</sub> = Supply voltage (Magnitude of V<sub>+</sub> and V<sub>-</sub>)
- IMAX = Maximum supply current of 1 amplifier
- V<sub>OUTMAX</sub> = Maximum output voltage swing of the application
- R<sub>L</sub> = Load resistance

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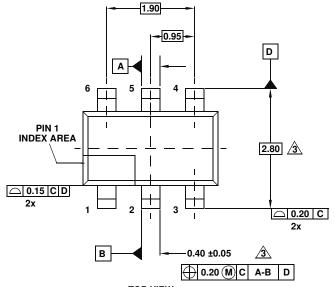
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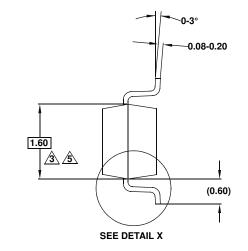
### **Package Outline Drawing**

#### P6.064A

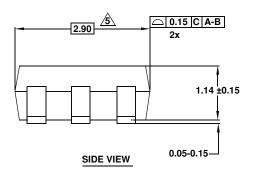
6 LEAD SMALL OUTLINE TRANSISTOR PLASTIC PACKAGE Rev 0, 2/10

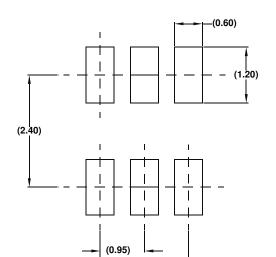


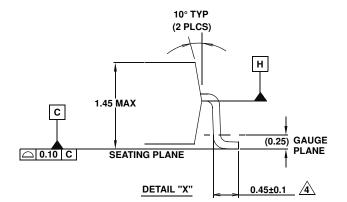
TOP VIEW



END VIEW







NOTES:

- 1. Dimensions are in millimeters.
- Dimensions in ( ) for Reference Only.
- 2. Dimensioning and tolerancing conform to ASME Y14.5M-1994.
- 3. Dimension is exclusive of mold flash, protrusions or gate burrs.
- 4. Foot length is measured at reference to guage plane.
- 5. This dimension is measured at Datum "H".
- 6. Package conforms to JEDEC MO-178AA.

 $0.22 \pm 0.03$ 

4° ± 4°

0.25

GAUGE PLANE 

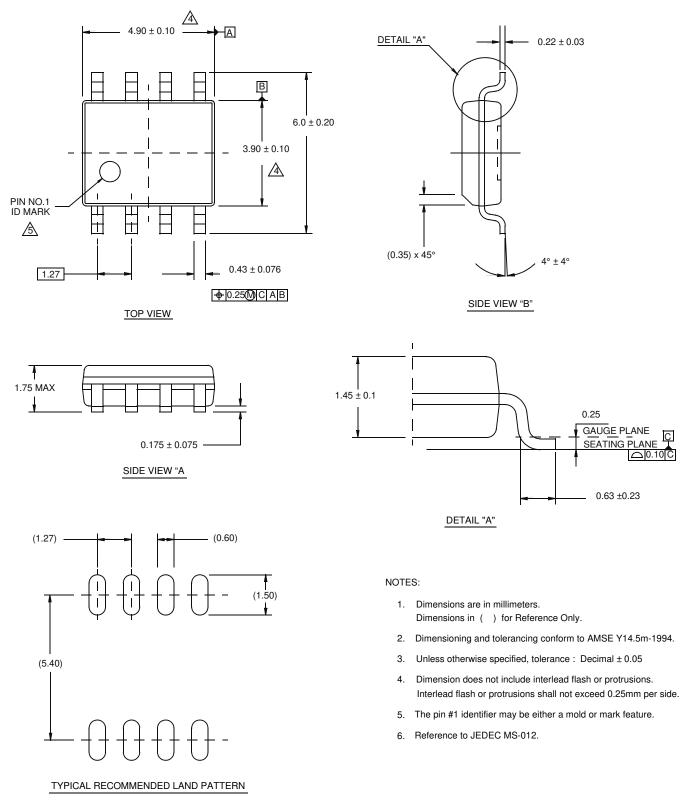
0.63 ±0.23

\_\_\_0.10 C

### **Package Outline Drawing**

#### M8.15E

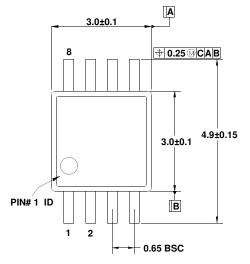
8 LEAD NARROW BODY SMALL OUTLINE PLASTIC PACKAGE Rev 0, 08/09



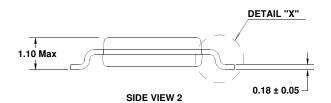
### **Package Outline Drawing**

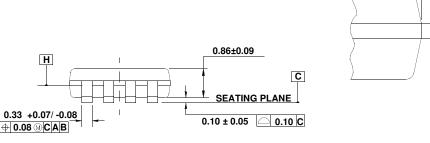
#### M8.118A

8 LEAD MINI SMALL OUTLINE PLASTIC PACKAGE (MSOP) Rev 0, 9/09





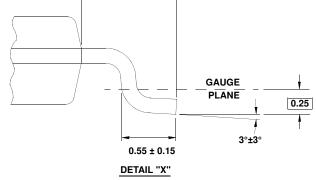




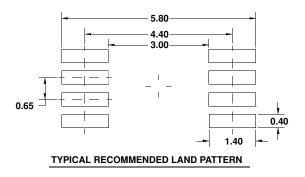
SIDE VIEW 1

Н

0.08 MCAB



0.95 BSC-



#### NOTES:

- 1. Dimensions are in millimeters.
- 2. Dimensioning and tolerancing conform to JEDEC MO-187-AA and AMSE Y14.5m-1994.
- 3. Plastic or metal protrusions of 0.15mm max per side are not included.
- Plastic interlead protrusions of 0.25mm max per side are not 4. included.
- 5. Dimensions "D" and "E1" are measured at Datum Plane "H".
- 6. This replaces existing drawing # MDP0043 MSOP 8L.